THYRISTOR MODULE (ISOLATED MOLD TYPE)

SG25AA

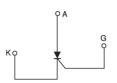


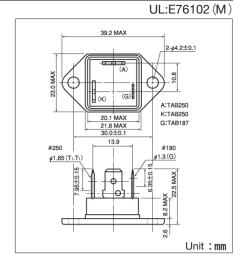




SG25AA is an isolated molded thyristor which is suitable for wide range of industrial and home electronics uses. **SG25AA** uses highly relible glass passivation.

- IT(AV)=25A
- high Surge Capability
- Tab terminals for easy wiring.





Maximum Ratings

Symbol	Item	Ratings			Unit
		SG25AA20	SG25AA40	SG25AA60	Onit
V RRM	Repetitive Peak Reverse Voltage	200	400	600	V
VRSM	Non-Repetitive Peak Reverse Voltage	240	480	720	V
VDRM	Repetitive Peak Off-State Voltage	200	400	600	V

Symbol	Item	Conditions	Ratings	Unit
IT (AV)	Average On-State Current	Single phase, half wave, 180° conduction, Tc: 70℃	25	Α
IT (RMS)	R.M.S. On-State Current	Single phase, half wave, 180° conduction, Tc: 70°C	39	Α
Ітѕм	Surge On-State Current	½cycle, 50Hz/60Hz, peak value, non-repetitive	450/500	Α
l²t	l²t	2~10ms	1040	A ² S
Рам	Peak Gate Power Dissipation		10	W
Pg (AV)	Average Gate Power Dissipation		1	W
lгдм	Peak Gate Current		3	Α
VFGM	Peak Gate Voltage(Forward)		10	V
V RGM	Peak Gate Voltage(Reverse)		5	V
di/dt	Critical Rate of Rise of On-State Current	Ig=100mA,Tj=25°C,VD= $\frac{1}{2}$ VDRM,dIg/dt=1A/ μ s	100	A/μs
Viso	Isolation Breakdown Voltage (R.M.S.)	A.C.1minute	2500	V
Tj	Operating Junction Temperature		− 40∼ + 125	°C
Tstg	Storage Temperature		− 40∼ + 125	°C
	Mounting Torque (M4)	Recommended Value 1.0~1.4 (10~14)	1.5 (15)	N·m (kgf·cm)
	Mass		23	g

■Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
IDRM	Repetitive Peak Off-State Current, max.	at VDRM, single phase, half wave, Tj=125℃	5	mA
IRRM	Repetitive Peak Reverse Current, max.	at VDRM, single phase, half wave, Tj=125℃	5	mA
Vтм	Peak On-State Voltage, max.	On-State Current 78A, Tj=25°C Inst. measurement	1.40	V
Igт / Vgт	Gate Trigger Current/Voltage, max.	Tj=25℃, Iτ=1A, VD=6V	40/3	mA/V
Vgd	Non-Trigger Gate, Voltage. min.	Tj=125℃, VD=1/2VDRM	0.2	V
tgt	Turn On Time, max.	IT=25A, IG=100mA, Tj=25°C, VD= $\frac{1}{2}$ VDRM, dIg/dt=1A/ μ s	10	μS
dv/dt	Critical Rate of Rise of Off-State Voltage, min.	Tj=125℃, VD=2⁄₃VDRM, Exponential wave.	100	V/μs
Ін	Holding Current, typ.	Tj=25℃	30	mA
Rth (j-c)	Thermal Impedance, max.	Junction to case	1.6	°C/W









